# NX3V1G384

# Low-ohmic single-pole single-throw analog switch

Rev. 01 — 18 September 2008

**Product data sheet** 

## 1. General description

The NX3V1G384 provides one single-pole single-throw analog switch function. It has two input/output terminals (Y and Z) and an active LOW enable input pin  $(\overline{E})$ . When pin  $\overline{E}$  is HIGH, the analog switch is turned off.

Schmitt trigger action at the enable input  $(\overline{E})$  makes the circuit tolerant to slower input rise and fall times across the entire  $V_{CC}$  range from 1.4 V to 3.6 V.

The NX3V1G384 allows signals with amplitude up to  $V_{CC}$  to be transmitted from Y to Z or from Z to Y. Its ultra-low ON resistance (0.3  $\Omega$ ) and flatness (0.1  $\Omega$ ) ensures minimal attenuation and distortion of transmitted signals.

### 2. Features

- Wide supply voltage range from 1.4 V to 3.6 V
- Very low ON resistance (peak):
  - 0.8  $\Omega$  (typical) at  $V_{CC} = 1.4 \text{ V}$
  - 0.5  $\Omega$  (typical) at  $V_{CC} = 1.65 \text{ V}$
  - 0.3 Ω (typical) at V<sub>CC</sub> = 2.3 V
  - 0.25  $\Omega$  (typical) at  $V_{CC} = 2.7 \text{ V}$
- High noise immunity
- ESD protection:
  - ◆ HBM JESD22-A114E Class 3A exceeds 7500 V
  - MM JESD22-A115-A exceeds 200 V
  - ◆ CDM AEC-Q100-011 revision B exceeds 1000 V
- CMOS low-power consumption
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level A
- Direct interface with TTL levels at 3.0 V
- Control input accepts voltages above supply voltage
- High current handling capability (500 mA continuous current under 3.3 V supply)
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

# 3. Applications

- Cell phone
- PDA
- Portable media player



### Low-ohmic single-pole single-throw analog switch

# 4. Ordering information

Table 1. Ordering information

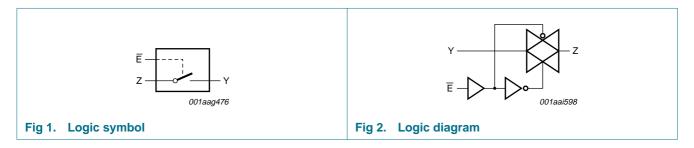
Type number	Package								
	Temperature range	Name	Description	Version					
NX3V1G384GW	–40 °C to +125 °C	TSSOP5	plastic thin shrink small outline package; 5 leads; body width 1.25 mm	SOT353-1					
NX3V1G384GM	–40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 $\times$ 1.45 $\times$ 0.5 mm	SOT886					

# 5. Marking

#### Table 2. Marking

Type number	Marking code
NX3V1G384GW	eL
NX3V1G384GM	eL

## 6. Functional diagram



# 7. Pinning information

## 7.1 Pinning



NX3V1G384\_1 © NXP B.V. 2008. All rights reserved.

#### Low-ohmic single-pole single-throw analog switch

### 7.2 Pin description

Table 3. Pin description

Symbol	Pin		Description
	SOT353-1	SOT886	
Υ	1	1	independent input or output
Z	2	2	independent output or input
GND	3	3	ground (0 V)
Ē	4	4	enable input (active LOW)
n.c.	-	5	not connected
$V_{CC}$	5	6	supply voltage

## 8. Functional description

Table 4. Function table[1]

Input E	Switch
L	ON
Н	OFF

<sup>[1]</sup> H = HIGH voltage level; L = LOW voltage level.

# 9. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC}$	supply voltage		-0.5	+4.6	V
VI	input voltage		[ <u>1]</u> –0.5	+4.6	V
$V_{SW}$	switch voltage		[2] -0.5	$V_{CC} + 0.5$	V
I <sub>IK</sub>	input clamping current	$V_1 < -0.5 \text{ V}$	-50	-	mΑ
I <sub>SK</sub>	switch clamping current	$V_I < -0.5 \text{ V or } V_I > V_{CC} + 0.5 \text{ V}$	-	±50	mΑ
I <sub>SW</sub>	switch current	$V_{SW} > -0.5 \text{ V or } V_{SW} < V_{CC} + 0.5 \text{ V};$ source or sink current	-	±500	mA
		$V_{SW}$ > -0.5 V or $V_{SW}$ < $V_{CC}$ + 0.5 V; pulsed at 1 ms duration, < 10% duty cycle; peak current	-	±750	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40  ^{\circ}\text{C} \text{ to } +125  ^{\circ}\text{C}$	[3] _	250	mW

<sup>[1]</sup> The minimum input voltage rating may be exceeded if the input current rating is observed.

<sup>[2]</sup> The minimum and maximum switch voltage ratings may be exceeded if the switch clamping current rating is observed.

<sup>[3]</sup> For TSSOP5 package: above 87.5 °C the value of  $P_{tot}$  derates linearly with 4.0 mW/K. For XSON6 packages: above 45 °C the value of  $P_{tot}$  derates linearly with 2.4 mW/K.

### Low-ohmic single-pole single-throw analog switch

# 10. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{CC}$	supply voltage		1.4	-	3.6	V
$V_{I}$	input voltage	enable input $\overline{E}$	0	-	3.6	V
$V_{\text{SW}}$	switch voltage		<u>[1]</u> 0	-	$V_{CC}$	V
T <sub>amb</sub>	ambient temperature		-40	-	+125	°C
$\Delta t/\Delta V$	input transition rise and fall rate	$V_{CC} = 1.4 \text{ V to } 3.6 \text{ V}$	[2] _	-	200	ns/V

<sup>[1]</sup> To avoid sinking GND current from of terminal Z when switch current flows in terminal Y, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal Z, no GND current will flow from terminal Y. In this case, there is no limit for the voltage drop across the switch.

## 11. Static characteristics

Table 7. Static characteristics

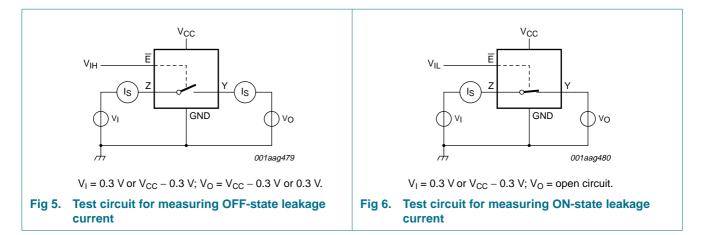
At recommended operating conditions; voltages are referenced to GND (ground 0 V).

Symbol	Parameter Conditions	Conditions	Tan	<sub>nb</sub> = 25	5 °C	T <sub>amb</sub> = -	Unit		
		Min	Тур	Max	Min	Max (85 °C)	Max (125 °C)		
$V_{IH}$	HIGH-level	V <sub>CC</sub> = 1.4 V to 1.95 V	0.65V <sub>CC</sub>	-	-	0.65V <sub>CC</sub>	-	-	V
	input voltage	V <sub>CC</sub> = 2.3 V to 2.7 V	1.7	-	-	1.7	-	-	V
		V <sub>CC</sub> = 2.7 V to 3.6 V	2.0	-	-	2.0	-	-	V
V <sub>IL</sub>	LOW-level	$V_{CC} = 1.4 \text{ V to } 1.95 \text{ V}$	-	-	0.35V <sub>CC</sub>	-	0.35V <sub>CC</sub>	0.35V <sub>CC</sub>	V
	input voltage	V <sub>CC</sub> = 2.3 V to 2.7 V	-	-	0.7	-	0.7	0.7	V
		V <sub>CC</sub> = 2.7 V to 3.6 V	-	-	0.8	-	0.8	0.8	V
II	input leakage current	enable input $\overline{E}$ ; V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 1.4 V to 3.6 V	-	-	-	-	±0.5	±1	μΑ
I <sub>S(OFF)</sub>	OFF-state leakage current	Y port; see Figure 5; $V_{CC} = 1.4 \text{ V to } 3.6 \text{ V};$	-	-	±5	-	±50	±500	nA
I <sub>S(ON)</sub>	ON-state leakage current	Z port; see Figure 6; $V_{CC} = 1.4 \text{ V to } 3.6 \text{ V};$	-	-	±5	-	±50	±500	nA
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $V_{CC} = 3.6$ V; $V_{SW} = GND$ or $V_{CC}$	-	-	±100	-	690	6000	nA
C <sub>I</sub>	input capacitance		-	1.0	-	-	-	-	pF
C <sub>S(OFF)</sub>	OFF-state capacitance		-	70	-	-	-	-	pF
$C_{S(ON)}$	ON-state capacitance		-	205	-	-	-	-	pF

<sup>[2]</sup> Applies to control signal levels.

## Low-ohmic single-pole single-throw analog switch

#### 11.1 Test circuits



#### 11.2 ON resistance

Table 8. Resistance R<sub>ON</sub>

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for graphs see Figure 8 to Figure 13.

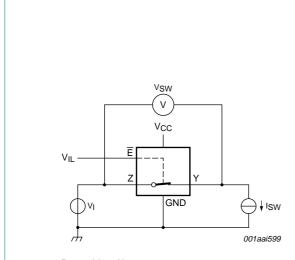
Symbol	Parameter	neter Conditions		$T_{amb}$ = -40 °C to +85 °C			T <sub>amb</sub> = -40 °	C to +125 °C	Unit
				Min	Typ[1]	Max	Min	Max	
R <sub>ON(peak)</sub>	ON resistance (peak)	$V_I = GND \text{ to } V_{CC};$ $I_{SW} = 100 \text{ mA}; \text{ see } \underline{Figure 7}$							
		V <sub>CC</sub> = 1.4 V		-	8.0	1.9	-	2.1	Ω
		V <sub>CC</sub> = 1.65 V		-	0.5	8.0	-	0.9	Ω
		$V_{CC} = 2.3 \text{ V}$		-	0.3	0.5	-	0.6	Ω
		$V_{CC} = 2.7 \text{ V}$		-	0.25	0.45	-	0.5	Ω
$R_{ON(flat)}$	ON resistance (flatness)	$V_I = GND \text{ to } V_{CC};$ $I_{SW} = 100 \text{ mA}$	[2]						
		$V_{CC} = 1.4 \text{ V}$		-	0.5	1.7	-	1.8	Ω
		V <sub>CC</sub> = 1.65 V		-	0.25	0.6	-	0.7	Ω
		$V_{CC} = 2.3 \text{ V}$		-	0.1	0.2	-	0.2	Ω
		$V_{CC} = 2.7 \text{ V}$		-	0.1	0.2	-	0.2	Ω

<sup>[1]</sup> Typical values are measured at  $T_{amb}$  = 25 °C.

<sup>[2]</sup> Flatness is defined as the difference between the maximum and minimum value of ON resistance measured at identical V<sub>CC</sub> and temperature.

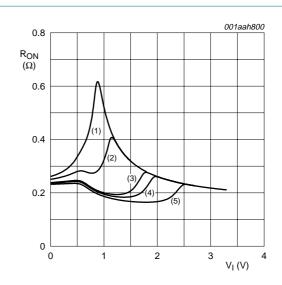
### Low-ohmic single-pole single-throw analog switch

## 11.3 ON resistance test circuit and graphs



 $R_{ON} = V_{SW} / I_{SW}$ 

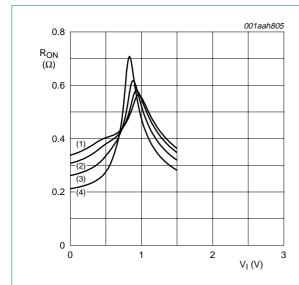
Fig 7. Test circuit for measuring ON resistance



- (1)  $V_{CC} = 1.5 \text{ V}.$
- (2)  $V_{CC} = 1.8 \text{ V}.$
- (3)  $V_{CC} = 2.5 \text{ V}.$
- (4)  $V_{CC} = 2.7 \text{ V}.$
- (5)  $V_{CC} = 3.3 \text{ V}.$

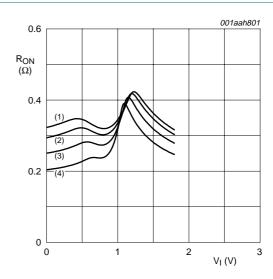
Measured at  $T_{amb}$  = 25 °C.

Fig 8. Typical ON resistance as a function of input voltage



- (1)  $T_{amb} = 125 \, ^{\circ}C$ .
- (2)  $T_{amb} = 85 \, ^{\circ}C$ .
- (3)  $T_{amb} = 25 \, ^{\circ}C$ .
- (4)  $T_{amb} = -40 \, ^{\circ}C$ .

Fig 9. ON resistance as a function of input voltage;  $V_{CC} = 1.5 \text{ V}$ 

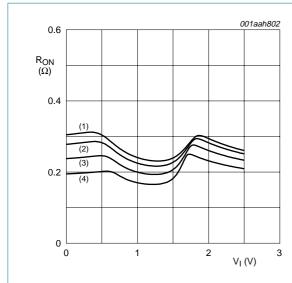


- (1)  $T_{amb} = 125 \, ^{\circ}C$ .
- (2)  $T_{amb} = 85 \, ^{\circ}C$ .
- (3)  $T_{amb} = 25 \, ^{\circ}C$ .
- (4)  $T_{amb} = -40 \, ^{\circ}C$ .

Fig 10. ON resistance as a function of input voltage;  $V_{CC} = 1.8 \text{ V}$ 

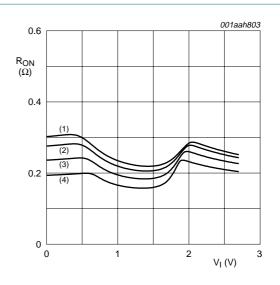
NX3V1G384\_1

### Low-ohmic single-pole single-throw analog switch



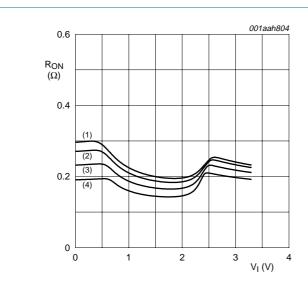
- (1)  $T_{amb} = 125 \, ^{\circ}C$ .
- (2)  $T_{amb} = 85 \, ^{\circ}C$ .
- (3)  $T_{amb} = 25 \, ^{\circ}C$ .
- (4)  $T_{amb} = -40 \, ^{\circ}C$ .

Fig 11. ON resistance as a function of input voltage;  $V_{CC} = 2.5 \text{ V}$ 



- (1)  $T_{amb} = 125 \, ^{\circ}C$ .
- (2)  $T_{amb} = 85 \, ^{\circ}C$ .
- (3)  $T_{amb} = 25 \, ^{\circ}C$ .
- (4)  $T_{amb} = -40 \, ^{\circ}C$ .

Fig 12. ON resistance as a function of input voltage;  $V_{CC} = 2.7 \text{ V}$ 



- (1)  $T_{amb} = 125 \, ^{\circ}C$ .
- (2)  $T_{amb} = 85 \, ^{\circ}C$ .
- (3)  $T_{amb} = 25 \, ^{\circ}C$ .
- (4)  $T_{amb} = -40 \, ^{\circ}C$ .

Fig 13. ON resistance as a function of input voltage;  $V_{CC} = 3.3 \text{ V}$ 

## Low-ohmic single-pole single-throw analog switch

# 12. Dynamic characteristics

Table 9. Dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for load circuit Figure 15.

Symbol	Parameter	Conditions		25 °C		–40 °C to +125 °C			Unit
			Min	Typ[1]	Max	Min	Max (85 °C)	Max (125 °C)	
$t_{en}$	enable time	E to Z or Y; see Figure 14							
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$	-	28	43	-	46	50	ns
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	-	23	36	-	39	43	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	-	18	28	-	30	32	ns
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	-	15	26	-	27	29	ns
t <sub>dis</sub>	disable time	E to Z or Y; see Figure 14							
		V <sub>CC</sub> = 1.4 V to 1.6 V	-	12	23	-	24	26	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	-	9	16	-	18	19	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	-	6	11	-	12	13	ns
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	-	5	10	-	11	12	ns

<sup>[1]</sup> Typical values are measured at  $T_{amb}$  = 25 °C and  $V_{CC}$  = 1.5 V, 1.8 V, 2.5 V and 3.3 V respectively.

## 12.1 Waveform and test circuits

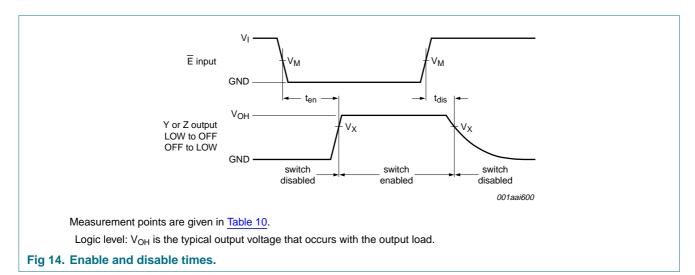


Table 10. Measurement points

Supply voltage	Input	Output
V <sub>CC</sub>	V <sub>M</sub>	V <sub>X</sub>
1.4 V to 3.6 V	0.5V <sub>CC</sub>	0.9V <sub>OH</sub>

NX3V1G384\_1 © NXP B.V. 2008. All rights reserved.

### Low-ohmic single-pole single-throw analog switch

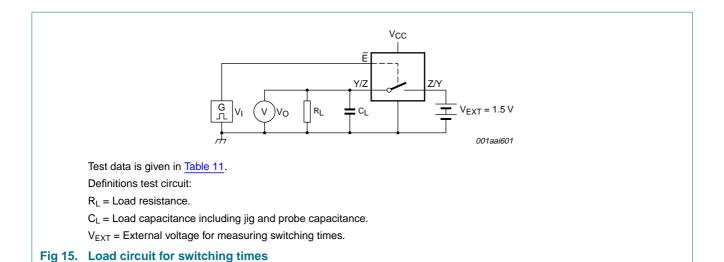


Table 11. Test data

Supply voltage	Input		Load	
V <sub>CC</sub>	VI	t <sub>r</sub> , t <sub>f</sub>	CL	R <sub>L</sub>
1.4 V to 3.6 V	V <sub>CC</sub>	≤ 2.5 ns	35 pF	50 Ω

## 12.2 Additional dynamic characteristics

Table 12. Additional dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V);  $V_l$  = GND or  $V_{CC}$  (unless otherwise specified);  $t_r$  =  $t_f \le 2.5$  ns.

Symbol	Parameter	Conditions			25 °C	25 °C	
					Тур	Max	
THD	total harmonic	$f_i$ = 20 Hz to 20 kHz; $R_L$ = 32 $\Omega$ ; see Figure 16	<u>[1]</u>				
	distortion	$V_{CC} = 1.4 \text{ V}; V_I = 1 \text{ V (p-p)}$		-	0.05	-	%
		$V_{CC} = 1.65 \text{ V}; V_I = 1.2 \text{ V (p-p)}$		-	0.03	-	%
		$V_{CC} = 2.3 \text{ V}; V_I = 1.5 \text{ V (p-p)}$		-	0.01	-	%
		$V_{CC} = 2.7 \text{ V}; V_{I} = 2 \text{ V (p-p)}$		-	0.01	-	%
f <sub>(-3dB)</sub>	-3 dB frequency	$R_L = 50 \Omega$ ; see Figure 17	<u>[1]</u>				
	response	V <sub>CC</sub> = 1.4 V to 3.6 V		-	25	-	MHz
$\alpha_{\text{iso}}$	isolation (OFF-state)	$f_i$ = 100 kHz; $R_L$ = 50 $\Omega$ ; see Figure 18	<u>[1]</u>				
		V <sub>CC</sub> = 1.4 V to 3.6 V		-	-90	-	dB
$V_{ct}$	crosstalk voltage	between digital inputs and switch; $f_i = 1 \text{ MHz}$ ; $C_L = 50 \text{ pF}$ ; $R_L = 50 \Omega$ ; see Figure 19					
		V <sub>CC</sub> = 1.4 V to 3.6 V		-	0.32	-	V
$Q_{inj}$	charge injection	$f_i$ = 1 MHz; $C_L$ = 0.1 nF; $R_L$ = 1 M $\Omega$ ; $V_{gen}$ = 0 V; $R_{gen}$ = 0 $\Omega$ ; see Figure 20					
		V <sub>CC</sub> = 1.5 V		-	6.5	-	рС
		V <sub>CC</sub> = 1.8 V		-	6.5	-	рС
		V <sub>CC</sub> = 2.5 V		-	6.5	-	рС
		$V_{CC} = 3.3 \text{ V}$		-	6.5	-	рС

Low-ohmic single-pole single-throw analog switch

#### [1] $f_i$ is biased at $0.5V_{CC}$ .

### 12.3 Test circuits

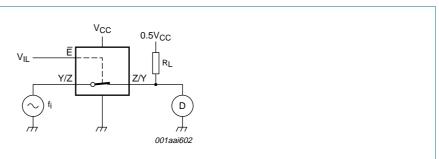
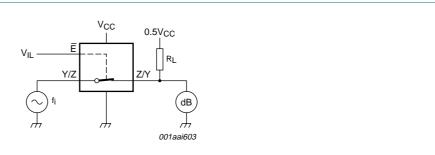
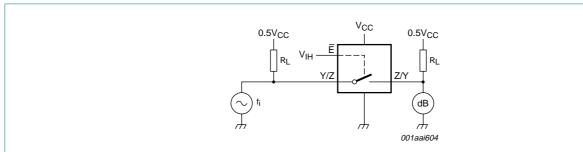


Fig 16. Test circuit for measuring total harmonic distortion



Adjust  $f_i$  voltage to obtain 0 dBm level at output. Increase  $f_i$  frequency until dB meter reads -3 dB.

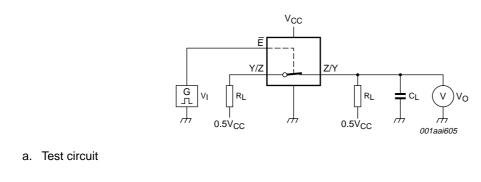
Fig 17. Test circuit for measuring the frequency response when channel is in ON-state



Adjust fi voltage to obtain 0 dBm level at input.

Fig 18. Test circuit for measuring isolation (OFF-state)

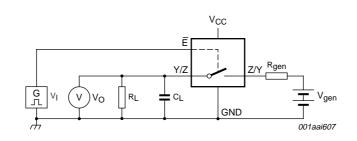
### Low-ohmic single-pole single-throw analog switch



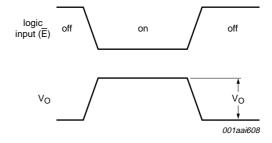
 $\begin{array}{c|c} logic \\ input \, (\overline{E}) \end{array} \qquad \text{off} \qquad \qquad \text{on} \qquad \begin{array}{c} \\ \\ V_{O} \end{array}$ 

b. input and output pulse definitions

Fig 19. Test circuit for measuring crosstalk voltage between digital inputs and switch



a. Test circuit.



b. Input and output pulse definitions.

$$\begin{split} & \text{Definition: } Q_{inj} = \Delta V_O \times C_L. \\ & \Delta V_O = \text{output voltage variation.} \\ & R_{gen} = \text{generator resistance.} \\ & V_{gen} = \text{generator voltage.} \end{split}$$

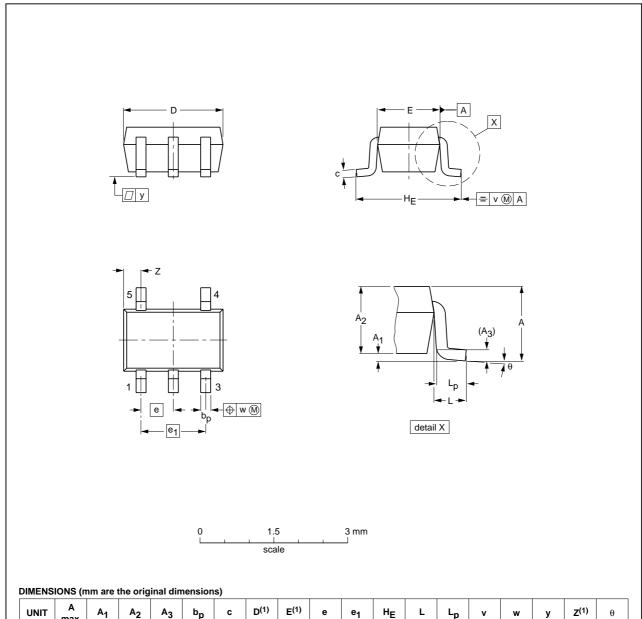
Fig 20. Test circuit for measuring charge injection

### Low-ohmic single-pole single-throw analog switch

# 13. Package outline

TSSOP5: plastic thin shrink small outline package; 5 leads; body width 1.25 mm

SOT353-1



UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	А3	bp	С	D <sup>(1)</sup>	E <sup>(1)</sup>	е	e <sub>1</sub>	HE	L	Lp	v	w	у	Z <sup>(1)</sup>	θ
mm	1.1	0.1 0	1.0 0.8	0.15	0.30 0.15	0.25 0.08	2.25 1.85	1.35 1.15	0.65	1.3	2.25 2.0	0.425	0.46 0.21	0.3	0.1	0.1	0.60 0.15	7° 0°

#### Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT353-1		MO-203	SC-88A			<del>-00-09-01</del> 03-02-19	

Fig 21. Package outline SOT353-1 (TSSOP5)

NX3V1G384\_1 © NXP B.V. 2008. All rights reserved.

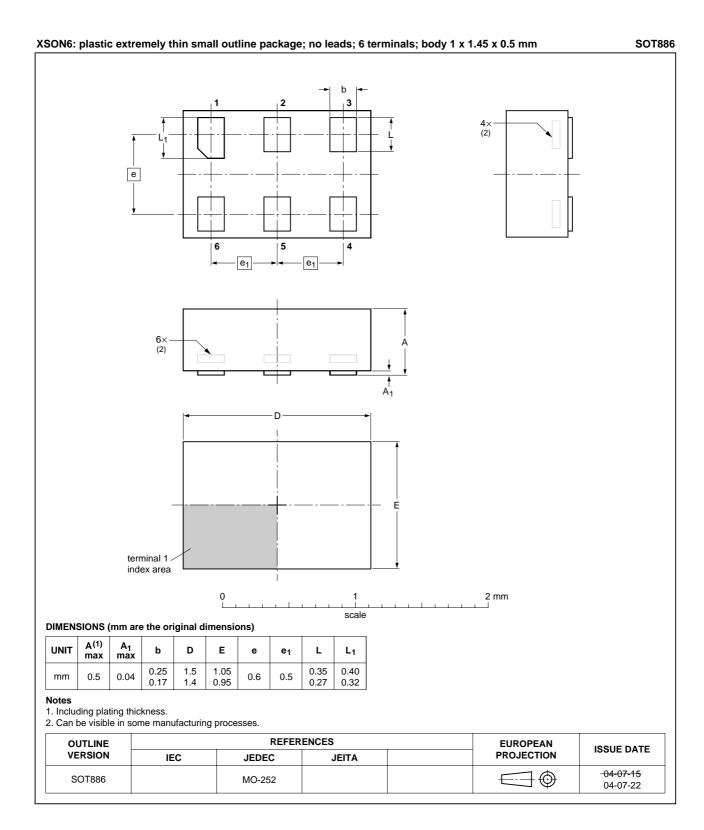


Fig 22. Package outline SOT886 (XSON6)

## Low-ohmic single-pole single-throw analog switch

## 14. Abbreviations

#### Table 13. Abbreviations

Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model
PDA	Personal Digital Assistant
TTL	Transistor-Transistor Logic

# 15. Revision history

#### Table 14. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
NX3V1G384_1	20080918	Product data sheet	-	-

#### Low-ohmic single-pole single-throw analog switch

## 16. Legal information

#### 16.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <a href="http://www.nxp.com">http://www.nxp.com</a>.

#### 16.2 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. NXP Semiconductors does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local NXP Semiconductors sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

#### 16.3 Disclaimers

**General** — Information in this document is believed to be accurate and reliable. However, NXP Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information.

Right to make changes — NXP Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

**Suitability for use** — NXP Semiconductors products are not designed, authorized or warranted to be suitable for use in medical, military, aircraft, space or life support equipment, nor in applications where failure or

malfunction of an NXP Semiconductors product can reasonably be expected to result in personal injury, death or severe property or environmental damage. NXP Semiconductors accepts no liability for inclusion and/or use of NXP Semiconductors products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

**Applications** — Applications that are described herein for any of these products are for illustrative purposes only. NXP Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) may cause permanent damage to the device. Limiting values are stress ratings only and operation of the device at these or any other conditions above those given in the Characteristics sections of this document is not implied. Exposure to limiting values for extended periods may affect device reliability.

Terms and conditions of sale — NXP Semiconductors products are sold subject to the general terms and conditions of commercial sale, as published at <a href="http://www.nxp.com/profile/terms">http://www.nxp.com/profile/terms</a>, including those pertaining to warranty, intellectual property rights infringement and limitation of liability, unless explicitly otherwise agreed to in writing by NXP Semiconductors. In case of any inconsistency or conflict between information in this document and such terms and conditions, the latter will prevail.

**No offer to sell or license** — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

#### 16.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

#### 17. Contact information

For more information, please visit: http://www.nxp.com

For sales office addresses, please send an email to: <a href="mailto:salesaddresses@nxp.com">salesaddresses@nxp.com</a>

### Low-ohmic single-pole single-throw analog switch

## 18. Contents

1	General description
2	Features
3	Applications
4	Ordering information 2
5	Marking 2
6	Functional diagram 2
7	Pinning information
7.1	Pinning
7.2	Pin description
8	Functional description 3
9	Limiting values 3
10	Recommended operating conditions 4
11	Static characteristics 4
11.1	Test circuits 5
11.2	ON resistance 5
11.3	ON resistance test circuit and graphs 6
12	Dynamic characteristics 8
12.1	Waveform and test circuits 8
12.2	Additional dynamic characteristics 9
12.3	Test circuits
13	Package outline 12
14	Abbreviations14
15	Revision history 14
16	Legal information
16.1	Data sheet status
16.2	Definitions
16.3	Disclaimers
16.4	Trademarks15
17	Contact information
12	Contents 16

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.

